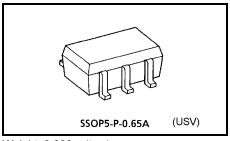
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG125FU

Bus Buffer with 3-STATE Output

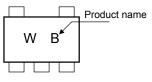
#### Features

- High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ at V<sub>CC</sub> = 3.0 V
- High-speed operation: t<sub>pd</sub> = 2.4 ns (typ.)
  - at V<sub>CC</sub> = 3.3 V,15pF
- Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V
- 5.5-V tolerant inputs.
- 3.6-V power down protection output.

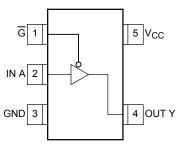


Weight: 0.006 g (typ.)

#### Marking



#### Pin Assignment (top view)



#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V
DC input voltage	VIN	-0.5~7.0	V
DC output voltage		-0.5~ 4.6 (Note 1)	v
Input diode current	Vout	-0.5~ V <sub>CC</sub> + 0.5 (Note 2)	v
Output diode current	I <sub>IK</sub>	-20	mA
DC output current	lok	-20 (Note 3)	mA
DC V <sub>CC</sub> /ground current	IOUT	±25	mA
Power dissipation	ICC	±50	mA
Storage temperature	PD	200	mW
Power supply voltage	T <sub>stg</sub>	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

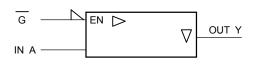
Note 1: V<sub>CC</sub> = 0V

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: VOUT < GND

# <u>TOSHIBA</u>

### **IEC Logic Symbol**



G	А	Y
Н	Х	Z
L	L	L
L	Н	Н

**Truth Table** 

### **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~3.6 (Note 4)	V	
Output voltage	VOUT	0~V <sub>CC</sub> (Note 5)	v	
		±8.0 (Note 6)		
	I <sub>OH</sub> /I <sub>OL</sub>	±4.0 (Note 7)		
Output Current		±3.0 (Note 8)	mA	
Sulput Current		±1.7 (Note 9)	ШA	
		±0.3 (Note 10)		
				±0.02 (Note 11)
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8: V<sub>CC</sub> = 1.65~1.95 V

Note 9:  $V_{CC} = 1.4 \sim 1.6 V$ 

Note 10: V<sub>CC</sub> = 1.1~1.3 V

Note 11:  $V_{CC} = 0.9 V$ 

Note 12:  $V_{IN} = 0.8{\sim}2.0$  V,  $V_{CC} = 3.0$  V

## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Symbol	Test Condition			1	Га = 25°С	)	Ta = -4	0~85°C	Unit			
		Symbol			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Onic			
					0.9	V <sub>CC</sub>	_	_	V <sub>CC</sub>	_				
					1.1~1.3	$V_{CC} \times 0.7$			V <sub>CC</sub> × 0.7	_				
	High level	VIH			1.4~1.6	V <sub>CC</sub> × 0.65			V <sub>CC</sub> × 0.65	_				
	0				1.65~ 1.95	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_				
					2.3~2.7	1.7	_	_	1.7	_				
Input voltaga					3.0~3.6	2.0	_	_	2.0	_	V			
Input voltage					0.9	_	_	GND		GND	v			
					1.1~1.3			$V_{CC} \times 0.3$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$				
	Low level	VIL		_	1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$				
		12				_		V <sub>CC</sub> × 0.35	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$				
					2.3~2.7	_	_	0.7	_	0.7	-			
					3.0~3.6	_		0.8		0.8				
		High level V <sub>OH</sub>	Уон		I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_			
					I <sub>OH</sub> = -0.3 mA	1.1~1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_			
	High level			V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_		
			or V <sub>IH</sub>	V <sub>IH</sub>	I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45	_			
							I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
Output voltage				I <sub>OH</sub> = -8.0 mA	3.0~3.6	2.48	_	_	2.48	_	V			
Output voltage				I <sub>OL</sub> = 0.02 mA	0.9	_	_	0.1		0.1	v			
				I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25				
	Low level	V <sub>OL</sub>	V <sub>IN</sub> =	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25				
			VIL	I <sub>OL</sub> = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45				
				I <sub>OL</sub> = 4.0 mA	2.3~2.7		_	0.4		0.4				
				I <sub>OL</sub> = 8.0 mA	3.0~3.6			0.4		0.4				
Input leakage curre	Input leakage current		V <sub>IN</sub> = 0~	-5.5V	0~3.6	_		±0.1		±1.0	μA			
3-state output off-s	state current	I <sub>OZ</sub>	$V_{IN} = V_I$ $V_{IN} = 0$	H or V <sub>IL</sub> -3.6V	0.9~3.6	_		1.0	_	10.0	μA			
Power off leakage	current	IOFF	V <sub>IN =</sub> 5.8 or V <sub>OUT</sub>	5V · = 3.6V	0.0			1.0	_	10.0	μΑ			
Quiescent supply of	current	ICC	$V_{IN} = V_{C}$	<sub>CC</sub> or GND	3.6	—	_	1.0		10.0	μA			

# AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		-	Ta = 25°0	)	Ta = -4	0~85°C	Unit
Characteristics	Symbol		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
			0.9		15.3				
			1.1~1.3	_	8.3	18.4	1.0	34.2	
		C <sub>L</sub> = 10 pF,	1.4~1.6		5.0	8.5	1.0	10.0	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.0	6.2	1.0	6.7	
			2.3~2.7		2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	17.7	_	_		
			1.1~1.3		9.6	21.5	1.0	37.2	
Propagation delay time	t <sub>pLH</sub>	C <sub>L</sub> = 15 pF,	1.4~1.6		5.6	9.3	1.0	11.2	ns
i topagatori delay time	t <sub>pHL</sub>	$R_L = 1 M\Omega$	1.65~ 1.95		4.5	6.9	1.0	7.1	113
			2.3~2.7	_	2.9	4.4	1.0	5.0	
			3.0~3.6		2.4	3.4	1.0	3.9	
			0.9	_	29.0	_	_		
		$C_L = 30$ pF, R <sub>L</sub> = 1 M $\Omega$	1.1~1.3		14.5	29.6	1.0	56.0	
			1.4~1.6		8.2	13.1	1.0	15.9	
			1.65~ 1.95		6.0	9.2	1.0	9.6	
			2.3~2.7		4.0	5.7	1.0	6.1	
			3.0~3.6		3.3	4.4	1.0	4.8	
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$ $C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	0.9		22.7	—	—	—	
			1.1~1.3		10.9	18.7	1.0	29.8	
			1.4~1.6		5.9	8.7	1.0	9.8	
			1.65~ 1.95		4.5	6.3	1.0	6.8	
			2.3~2.7		3.1	4.2	1.0	4.5	
			3.0~3.6		2.4	3.2	1.0	3.5	
		$\begin{array}{l} C_L = 15 \ pF, \\ R_L = 100 \ k\Omega \end{array}$	0.9		25.3	_	_	_	
			1.1~1.3	_	11.9	20.7	1.0	34.7	
Output enable time	t <sub>pZL</sub>		1.4~1.6	_	6.5	9.5	1.0	11.1	ns
	<sup>t</sup> pZH	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		4.9	6.8	1.0	7.2	
		-	2.3~2.7	_	3.3	4.4	1.0	4.8	
			3.0~3.6		2.5	3.4	1.0	3.7	
		$\begin{array}{l} C_L = 30 \ pF, \\ R_L = 100 \ k\Omega \end{array}$	0.9		37.7	_		_	
			1.1~1.3	_	17.1	30.7	1.0	50.5	
			1.4~1.6	_	8.8	13.1	1.0	15.1	
		$\begin{array}{l} C_{L}=30 \text{ pF},\\ R_{L}=5 \text{ k}\Omega \end{array}$	1.65~ 1.95	_	6.6	9.2	1.0	9.9	
			2.3~2.7	_	4.1	5.4	1.0	5.8	
			3.0~3.6	_	3.1	4.1	1.0	4.5	

# **TOSHIBA**

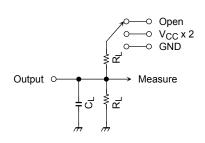
Characteristics	Symbol	Test Condition		-	Ta = 25°0	2	Ta = -4	0~85°C	Unit			
Cildiacteristics	Symbol			Min	Тур.	Max	Min	Max	Unit			
		$\begin{array}{l} C_L = 10 \ pF, \\ R_L = 100 \ k\Omega \end{array}$	0.9	_	117.6	_	_	_				
			1.1~1.3	_	9.2	16.0	1.0	22.4				
			1.4~1.6		7.1	9.1	1.0	10.4				
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	6.7	8.3	1.0	9.0				
		-	2.3~2.7	_	6.2	7.3	1.0	8.8				
			3.0~3.6	_	5.8	6.9	1.0	7.6				
	<sup>t</sup> pLZ tpHZ	$\begin{array}{l} C_L = 15 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9	_	139.2		_					
		$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$ $C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	1.1~1.3		10.0	16.9	1.0	25.1	ns			
Output disable time			1.4~1.6	_	7.8	9.8	1.0	11.3				
						1.65~ 1.95	_	7.4	9.2	1.0	10.6	
					2.3~2.7	_	7.0	8.2	1.0	10.3		
			3.0~3.6	_	6.8	7.7	1.0	9.5				
			0.9		230.8		_	_				
			1.1~1.3		14.0	20.8	1.0	31.9				
			1.4~1.6		12.2	13.5	1.0	14.9				
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		11.5	13.0	1.0	13.9				
			2.3~2.7		11.3	12.2	1.0	13.5				
			3.0~3.6		10.9	11.8	1.0	12.9				
Input capacitance	C <sub>IN</sub>	—	3.6		3		_		pF			
Power dissipation capacitance	C <sub>PD</sub>	(Note13)	0.9 ~ 3.6	_	8	_	—		pF			

Note 13:CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **AC Characteristics Measurement Circuit**

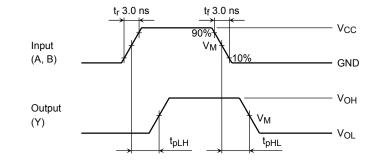


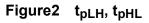
Characteristics	Switch
tpLH, tpHL	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	V <sub>CC</sub> x 2
<sup>t</sup> pHZ, <sup>t</sup> pZH	GND

# Figure1 t<sub>pLH</sub>, t<sub>pHL</sub>

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#### **AC Characteristics Measurement Circuit**





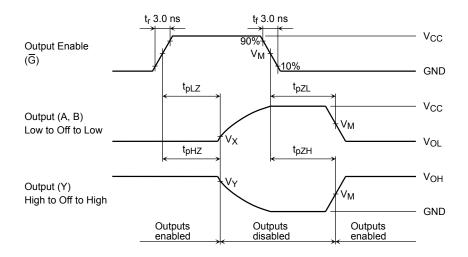
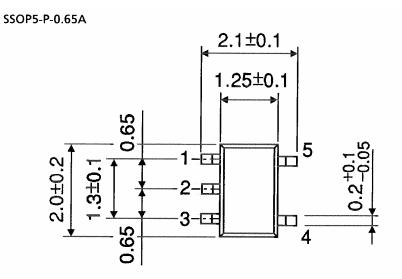
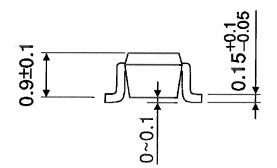


Figure3 t<sub>pLZ</sub>, t<sub>pHZ</sub>, t<sub>pZL</sub>, t<sub>pZH</sub>

UNIT	V <sub>CC</sub>									
UNIT	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V				
VM	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2				
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.1 V	V <sub>OL</sub> + 0.1 V	V <sub>OL</sub> + 0.1 V				
VY	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.1 V	V <sub>OH</sub> - 0.1 V	V <sub>OH</sub> - 0.1 V				

# Package Dimensions





Weight: 0.006 g (typ.)

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Unit : mm

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20070701-EN GENERAL

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